

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	1	(semiconductor and memory and matrix and row-direction and column-direction and (device adj isolation adj films) and (first adj conductive adj layers) and (lower adj inter-electrode adj dielectric)).clm.	US-PGPUB	OR	ON	2005/09/14 09:21
S1	1520	((memory adj cell) with (matrix or array)) and transistor and (dielectric or (device adj isolation)) and (silicon and nitrogen)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/12 10:20
S2	211	S1 and (memory and ((device adj (separation or isolation)) or dielectric)).ab.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/12 10:17
S3	1579	((memory adj cell) with (matrix or array)) and transistor and (((trench adj isolation) or STI) or dielectric or (device adj isolation)) and (silicon and nitrogen)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/12 10:22
S4	741	S3 and leakage	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/12 10:22
S5	374	S4 and (second with dielectric)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/12 10:22
S6	199	S5 and (dielectric with leakage)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/12 10:23
S7	24	S6 and STI	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/12 10:30
S8	915	S3 and (wordline or (word adj line)) and (bitline or (bit adj line))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/12 10:31

S9	53	S8 and (dielectric or isolation).ti.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/12 10:37
S10	219	S8 and ((bitline or (bit adj line)) with (dielectric or isolation))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/12 10:56
S11	4	S9 and ((bitline or (bit adj line)) with (dielectric or isolation)).ab.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/12 10:38
S12	1969	Ozawa.in. and memory	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/12 10:56
S13	75	S12 and Yoshio.in.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/12 10:56
S14	21	S13 and dielectric	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/12 10:57
S15	9	("6133097" "6171908" "6174771" "6184088" "6194269" "6323085" "6337250" "6399441" "6486508").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2005/09/12 11:19
S16	13	("4769787" "5621233" "5679591" "5789776" "5859459" "6005270" "6091101" "6143607" "6198658" "6431915" "6438030" "6531360" "RE35356").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2005/09/12 11:46
S17	23	("5789776").URPN.	USPAT	OR	ON	2005/09/12 12:03
S18	0	2001-168306	JPO	OR	ON	2005/09/12 12:03
S19	1	"2001168306"	JPO	OR	ON	2005/09/12 12:05
S20	20829	(IGUCHI, SUNAO).in.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/12 12:05

S21	9725	(IGUCHI).in.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/12 12:05
S22	11121	S20 and (sunao).in.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/12 12:06
S23	17	S21 and (sunao).in.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/12 12:26
S24	2051	(himeno).in.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/12 12:26
S25	52	S24 and (yoshiaki).in.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/12 12:27
S26	15	S25 and memory	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/12 12:27
S27	11	("5874353" "6037625" "6187651" "6190966" "6222225" "6228713" "6255689" "6342715" "6351008" "6369416" "6373095").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2005/09/12 13:10
S28	2657	257/296.ccls.	USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/13 12:51
S29	1587	257/315.ccls.	USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/13 12:43
S30	635	257/324.ccls.	USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/13 13:07
S31	983	257/390.ccls.	USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/13 13:12

S32	616	257/410.ccls.	USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/13 14:13
S33	616	257/410.ccls.	USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/13 14:13